



EC4AW8 SERIES

3.96-6 WATT 8:1 INPUT RANGE

ISOLATED DC-DC CONVERTER

Features

- Efficiency up to 87%
- Fixed Switching Frequency
- Positive Remote On/Off (Optional)
- Fully Protected (OVP/OCV/UVLO)
- 3000Vdc I/O Isolation
- Operating Temperature -40 to +105°C
- 1.25"x0.8"x0.4" Size Meet Industrial Standard
- Safety Meets IEC/EN/UL 62368-1
- Meets EN 55032 Class A without External Filter
- 5000m Operating Altitude



MODEL NUMBER	INPUT VOLTAGE	OUTPUT VOLTAGE	OUTPUT CURRENT		INPUT CURRENT 48V _{in} (TYP.)		% EFF (TYP.)			CAPACITOR LOAD MAX.
			MIN.	MAX.	NO LOAD	FULL LOAD	12V _{in}	24V _{in}	48V _{in}	
EC4AW8-48S33	9-75 VDC	3.3 VDC	0 mA	1200 mA	5 mA	109 mA	77	78	76	1800uF
EC4AW8-48S05	9-75 VDC	5 VDC	0 mA	1000 mA	5 mA	130 mA	82	83	80	1200uF
EC4AW8-48S12	9-75 VDC	12 VDC	0 mA	500mA	5 mA	147 mA	85	87	85	1000uF
EC4AW8-48S15	9-75 VDC	15 VDC	0 mA	400 mA	7 mA	146 mA	86	87	86	470uF
EC4AW8-48D05	9-75 VDC	±5 VDC	0 mA	±500 mA	5 mA	130 mA	82	83	80	600uF
EC4AW8-48D12	9-75 VDC	±12 VDC	0 mA	±250 mA	5 mA	147 mA	85	86	85	250uF
EC4AW8-48D15	9-75 VDC	±15 VDC	0 mA	±200 mA	8 mA	148 mA	85	87	85	200uF

NOTE:

1. Nominal input voltage 12V_{dc}, 24V_{dc} or 48V_{dc}.
2. Measured at nominal input voltage.

PART NUMBER

Series	Nominal Input Voltage	Number of Outputs	Nominal Output Voltage	Remote On/Off Logic
EC4AW8-	II	O	XX	L
EC4AW8	48 : 48 VDC	S : Single D : Dual	33 : 3.3VDC 05 : 5.0VDC 12 : 12VDC 15 : 15VDC 05 : ±5.0 VDC 12 : ±12 VDC 15 : ±15 VDC	Blank : None P : Positive

Part Number Example:

EC4AW8-48S12: 6W, 8:1 9-75Vdc Input, Single 12Vdc Output

EC4AW8-48S12P: 6W, 8:1 9-75Vdc Input, Single 12Vdc Output, Positive Logic



EC4AW8 Series

TECHNICAL SPECIFICATIONS

(All specifications are typical at nominal input, full load at 25°C unless otherwise noted.)

ABSOLUTE MAXIMUM RATINGS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Input Voltage	Continuous	All	-0.3		75	V _{dc}
Input Surge Voltage	100ms max.	All			100	V _{dc}
Operating Temperature	With de-rating, above 80°C	3.3Vo 5Vo ±5Vo	-40		105	°C
	With de-rating, above 85°C	Others	-40		105	°C
Operating Case Temperature	At the center part of case plate	All	-40		115	°C
Storage Temperature		All	-55		125	°C

INPUT CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Operating Input Voltage		All	9	48	75	V _{dc}
Input Under Voltage Lockout						
Turn-On Voltage Threshold	100% Load	All	7.6	8.1	8.8	V _{dc}
Turn-Off Voltage Threshold	100% Load	All	7.0	7.5	8.0	V _{dc}
Lockout Hysteresis Voltage	100% Load	All		0.6		V _{dc}
Maximum Input Current	V _{in} =9V _{dc} , Full load	All		810		mA
No-Load Input Current	V _{in} =48V _{dc} , I _o =0A	See Model Number Table				mA
Input Filter	Pi Type	All				
Inrush Current (I _{2t})	As per ETS300 132-2	All			0.1	A ² s
Input Reflected Ripple Current	V _{in} =Nominal, L=12uH, Load=Full load	All		30		mA

OUTPUT CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Voltage Set Point Accuracy	V _{in} =48V _{dc} , Full load, T _c =25°C	3.3Vo Others	-2.0 -1.5		+2.0 +1.5	%
Output Voltage Balance	V _{in} =48V _{dc} , Full load, T _c =25°C	±5Vo Others	-2.0 -1.0		+2.0 +1.0	%
Output Voltage Regulation						
Load Regulation	Full load to no load	Single Dual			±0.5 ±1.0	%
Line Regulation	V _{in} =High line to low line, full load	All			±0.5	%
Cross Regulation	Asymmetrical load 25%/100%	Dual			±5	%
Temperature Coefficient	T _c =-40°C to 85°C	All			±0.05	%/°C
Over Voltage Protection	Built-in a zener diode component to clamp output voltage	3.3Vo 5Vo 12Vo 15Vo ±5Vo ±12Vo ±15Vo	3.795 5.75 13.8 17.25 ±5.75 ±13.8 ±17.25	4.15 6.6 15.6 19.15 ±6.6 ±15.6 ±19.15	4.62 7 16.8 21 ±7 ±16.8 ±21	V
Output Voltage Ripple and Noise (20MHz bandwidth)						
Peak-to-Peak	Full load, 1uF ceramic capacitors	All			100	mV
Output Current Range	V _{in} = 9 to 75V _{dc}	See Model Number Table				A
Over Current Protection	Hiccup mode. Auto recovery	All	110		230	%
Short Circuit Protection		All	Continuous, Auto Recovery			
External Load Capacitance	Full load (resistive)	See Model Number Table				uF



EC4AW8 Series

EFFICIENCY

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
100% Load	$V_{in}=12V_{dc}, 24V_{dc}, 48V_{dc}$	All	See Model Number Table			%

DYNAMIC CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Output Voltage Current Transient						
Error Band	75% to 100% of I_{o_max} , step load change $dI/dt=0.1A/us$ (within 1% V_{out} nominal)	All			±5	%
Recovery Time		All			250	us
Turn-On Delay and Rise Time	Full load (Constant resistive load)					
Turn-On Delay Time, From Input	V_{in_min} to 10% V_{o_set} , Power up	All		10		ms
Output Voltage Rise Time	10% V_{o_set} to 90% V_{o_set}	All		8		ms

ISOLATION CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Isolation Voltage (100% factory Hi-Pot tested @2sec.)	1 Minute; input to output	All			3000	V_{dc}
Isolation Resistance	Input to output	All	1000			MΩ
Isolation Capacitance	Input to output	All		1000		pF

FEATURE CHARACTERISTICS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
Switching Frequency	Pulse width modulation (PWM), Fixed	All		300		KHz
On/Off Control, Positive Remote On/Off Logic, Refer to $-V_{in}$ Pin						
Logic High (Module Off)	$V_{on/off}$ at $I_{on/off}=1.0mA$	All	0		1.2	V_{dc}
Logic Low (Module On)	$V_{on/off}$ at $I_{on/off}=0.0uA$, Pin open=on	All	3.5 or Open Circuit		75	V_{dc}
Off Converter Input Current	Shutdown input idle current	All			1	mA

GENERAL SPECIFICATIONS

PARAMETER	NOTES and CONDITIONS	Device	Min.	Typ.	Max.	Units
MTBF	$I_o=100\%$ of I_{o_max} ; MIL-HDBK - 217F_Notice 1, GB, 25°C	3.3Vo		3520		K hours
		5Vo		3266		
		12Vo		2780		
		15Vo		3089		
		±5Vo		3156		
		±12Vo		2526		
		±15Vo		2802		
Weight		All		12.3		grams
Case Material	Plastic, DAP, UL 94V-0					
Base plate Material	Non-conductive base					
Potting Material	UL 94V-0					
Pin Material	Base: Copper with Steel Plating: Barrel Tin					
Shock/Vibration	MIL-STD-810F Compliant					
Humidity	95% RH max. Non condensing					
Altitude	5000m Operating altitude, 12000m Transport altitude					
Thermal Shock	MIL-STD-810F					

EMC SPECIFICATIONS (External components required, please refer to application note.)

EMI Conduction	Meets EN 55032 Class A (without external filter), Meets EN 55032 Class B (with external filter)					
EMI Radiation	Meets EN 55032 Class A & Class B (without external filter)					
ESD	Meets EN 61000-4-2 Level 2: Air ±8kV, Contact ±4kV					Perf. Criteria A



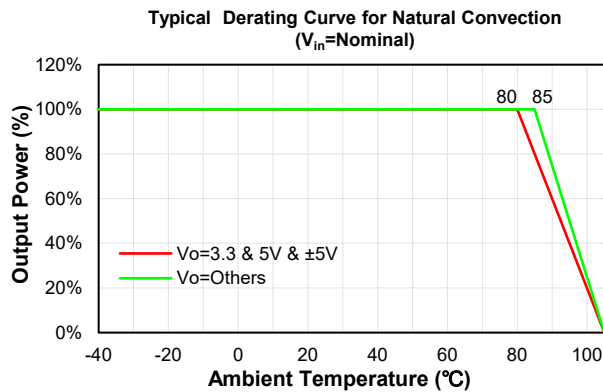
EC4AW8 Series

GENERAL SPECIFICATIONS

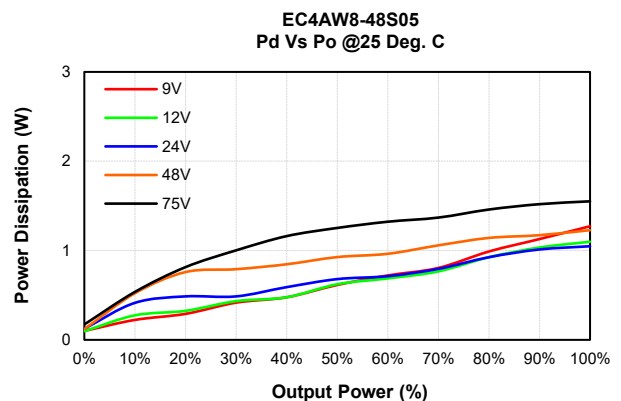
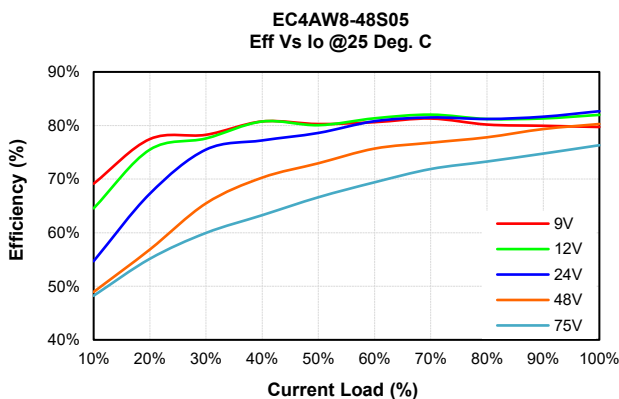
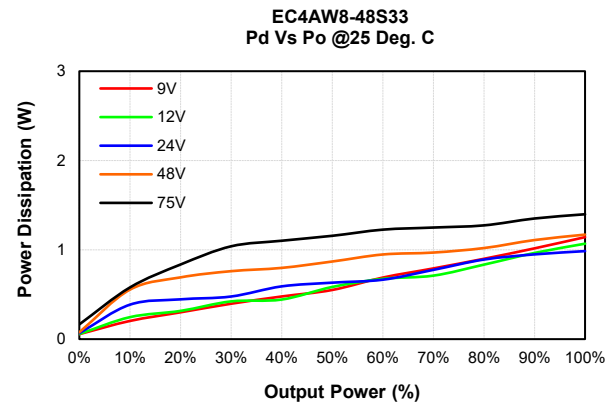
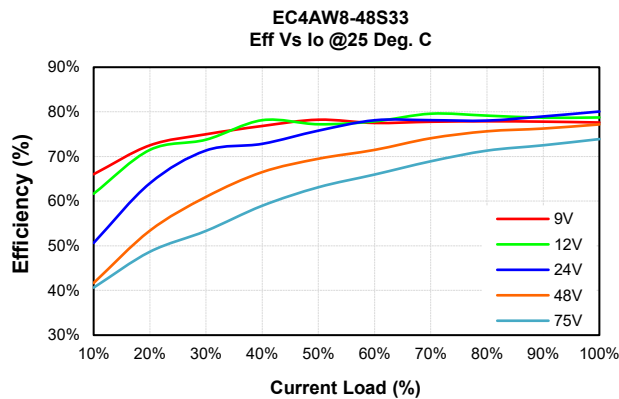
Radiated Immunity	Meets EN 61000-4-3 Level 2: 80~1000MHz, 3V/m	Perf. Criteria A
Fast Transient	Meets EN 61000-4-4 Level 2: On power input port, $\pm 0.5\text{kV}$, external input TVS required	Perf. Criteria A
Surge	Meets EN 61000-4-5 Level 2: Line to line, $\pm 0.5\text{kV}$, external input TVS required	Perf. Criteria A
Conducted Immunity	Meets EN 61000-4-6 Level 2: 0.15~80MHz, 3V	Perf. Criteria A
Application Note Link		EC4AW8 Series App Notes
Packaging Information Link		Packaging Information

CHARACTERISTIC CURVE

Power Derating Curve



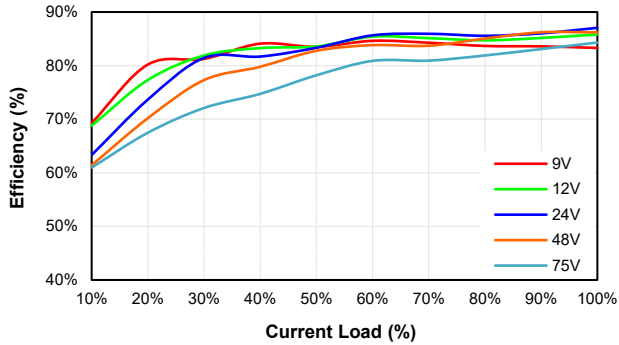
Performance Data



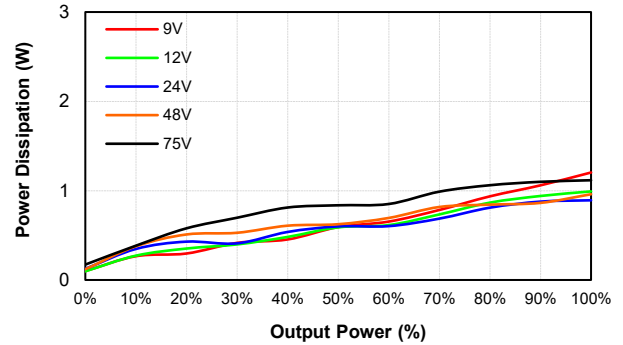


EC4AW8 Series

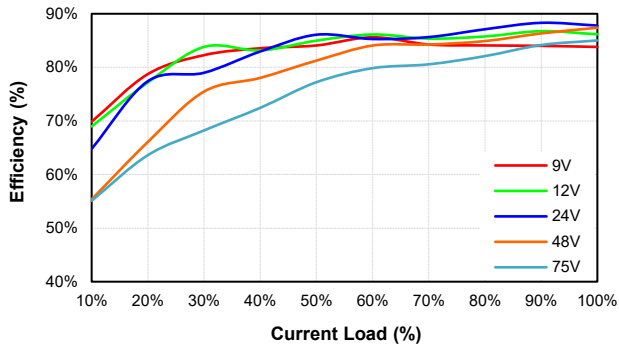
EC4AW8-48S12
Eff Vs Io @25 Deg. C



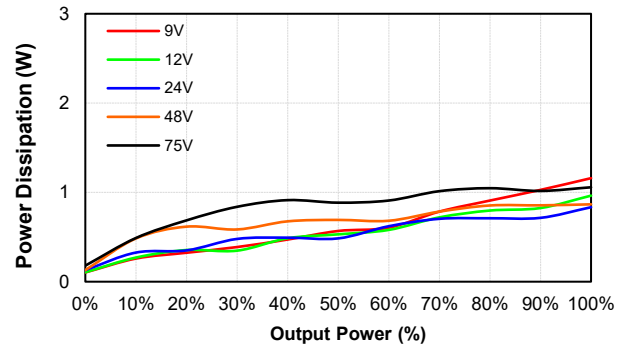
EC4AW8-48S12
Pd Vs Po @25 Deg. C



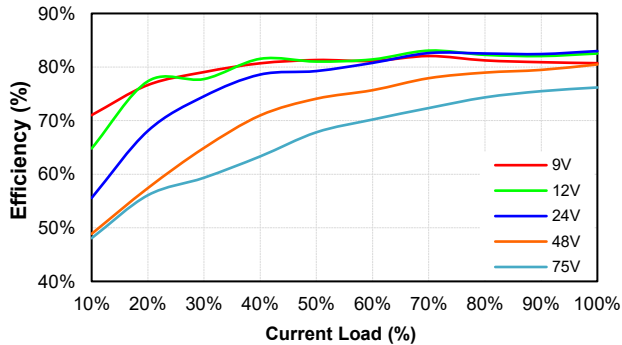
EC4AW8-48S15
Eff Vs Io @25 Deg. C



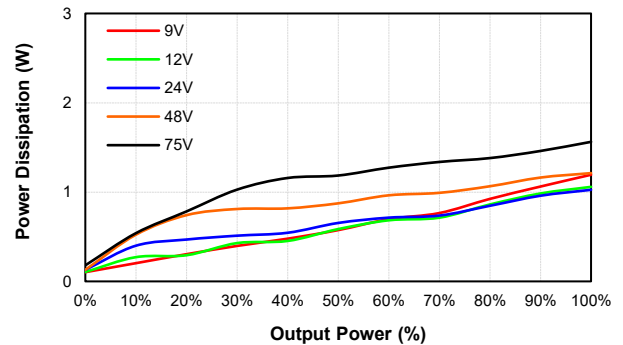
EC4AW8-48S15
Pd Vs Po @25 Deg. C



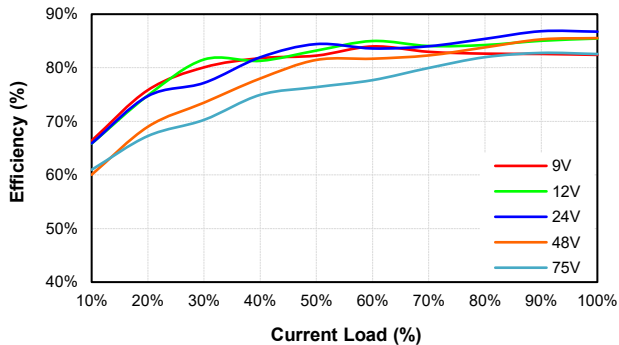
EC4AW8-48D05
Eff Vs Io @25 Deg. C



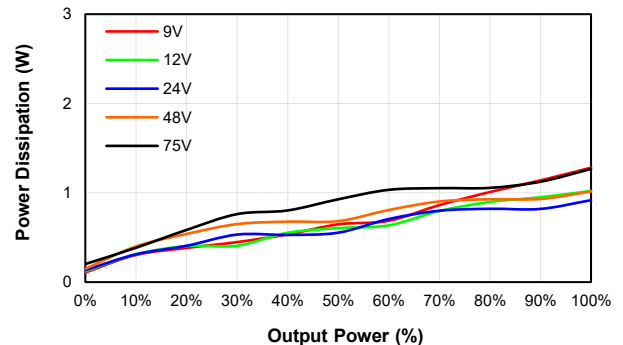
EC4AW8-48D05
Pd Vs Po @25 Deg. C



EC4AW8-48D12
Eff Vs Io @25 Deg. C



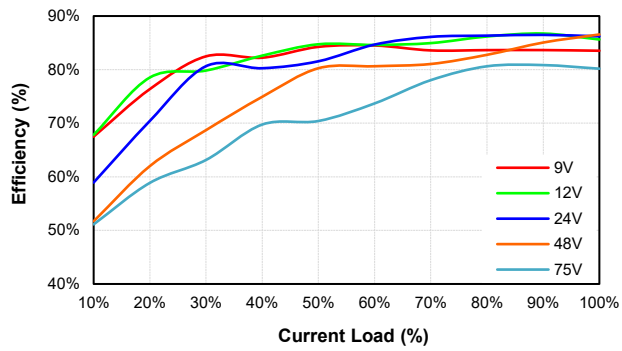
EC4AW8-48D12
Pd Vs Po @25 Deg. C



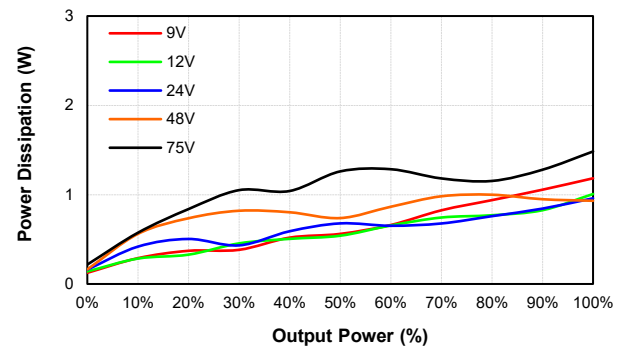


EC4AW8 Series

EC4AW8-48D15
Eff Vs Io @25 Deg. C



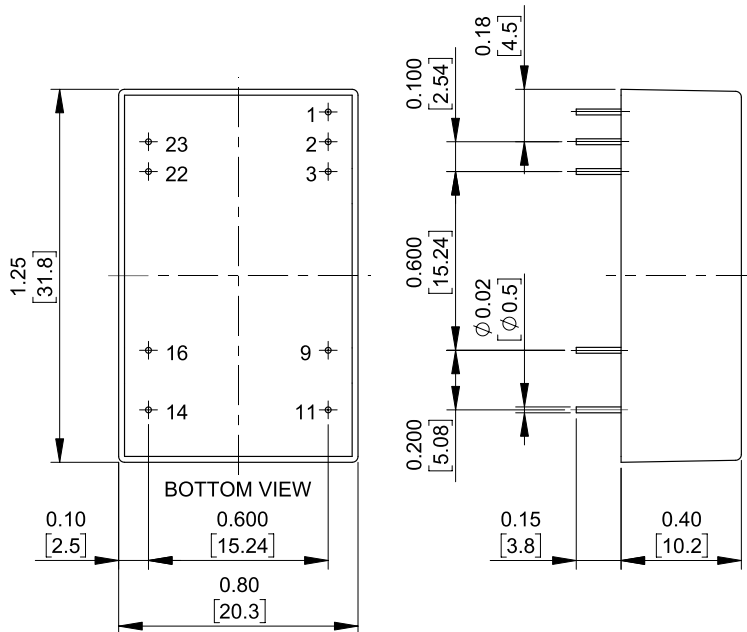
EC4AW8-48D15
Pd Vs Po @25 Deg. C





EC4AW8 Series

MECHANICAL SPECIFICATION



All Dimensions in Inches[mm]

Tolerance Inches: x.xx=±0.02, x.xxx=±0.010

Millimeters: x.x=±0.5, x.xx=±0.25

Pin Connection

Pin	Single	Dual
1	NP Remote On/Off(Optional)	
2,3	-V Input	-V Input
9	NC	Common
11	NC	-V Output
14	+V Output	+V Output
16	-V Output	Common
22,23	+V Input	+V Input

Note: Pin Size is $\phi 0.02 \pm 0.002$ Inch [$\phi 0.5 \pm 0.05$ mm]

NP-No Pin

NC-No Connection with Pin